## Ab initio charge, spin and orbital energy scales in LaM nO<sub>3</sub>

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The rst-principles SIC-LSD theory is utilized to study electronic, magnetic and orbital phenom ena in LaM nO<sub>3</sub>. The correct ground state is found, which is antiferro orbitally ordered with the spin magnetic moments antiferrom agnetically aligned. Jahn-Teller energies are found to be the largest energy scale. In addition it is the Jahn-Teller interaction which is the dom inant e ect in realising orbital order, and the electronic e ects alone do not su ce.

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There are several transition m etal com pounds in which the orbital degeneracy is broken spontaneously. Exam ples are KCuF<sub>3</sub>, [1]V<sub>2</sub>O<sub>3</sub>, [2] and them anganites, [3] which are the subject of the present study. In the manganites, the crystal eld associated with  $M nO_6$  octahedra splits the manganese d levels into a lower lying  $t_{2g}$  triplet and an upper eq doublet. The t<sub>2q</sub> states are highly localized whereas an electron in one of the  $e_{\alpha}$  states is potentially itinerant. The M n<sup>4+</sup> ion in C aM nO<sub>3</sub> has a fully occupied majority  $t_{2q}$  manifold and empty  $e_q$  states, which form a strongly localized core spin  $S = \frac{3}{2}$ . The M n<sup>3+</sup> ion in LaM nO<sub>3</sub>, on the other hand, has an additionald electron which, due to the strong intra-atom ic exchange, populates one of the  $e_q$  states, form ing an S = 2 spin, and which gives rise to a Jahn-Teller (JT) instability. In this system each of the oxygen ions is a neighbour to two M n ions and hence the local distortions of the lattice must be arranged in such a way as to m in im ize the energy for the whole crystal. This gives rise to Mn-O bond lengths of 1.90 and 2.18A within the manganese oxygen plane, com pared with 1.96A for the hypothetical cubic system . The  $e_{\alpha}$  states rotate to form an orbitally ordered lattice of  $d_{3x^2}$   $r^2$  and  $d_{3y^2}$   $r^2$  orbitals in the manganese oxygen plane[4], shown schematically in Fig. 1.

This paper reports a rst-principles study of charge, spin and orbital energy scales in LaM nO<sub>3</sub>, with the emphasis on orbital ordering (00), based upon the self-interaction corrected (SIC) local spin-density (LSD) theory, [5, 6] which allow sd-electron localization to be distinguished from itinerancy, in an ab initio manner.[7,8] Not only does the SIC allow the localization of an orbital of any symmetry, but the SIC-LSD total energies can be minimized with respect to the number of localized orbitals and their orientation. In addition, m in im ization with respect to the num ber of localized orbitals yields valency which is de ned as an integer num ber of electrons available for band form ation,  $N_{val} = Z = N_{core} = N_{SIC}$ , where  $\rm Z$  is the atom ic number,  $\rm N_{\, core}$  is the number of core (and sem i-core) states, and N<sub>SIC</sub> the num ber of selfinteraction corrected (localized) states. Furtherm ore, in the SIC-LSD the occupation of each localized orbital is

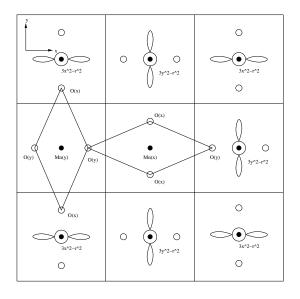


FIG.1: Simplied view of the manganese oxygen plane in LaM nO<sub>3</sub>. The small black circles represent the manganese atom s, while the open circles mark the positions of the oxygens. The distortion has been exaggerated to show clearly that the manganese oxygen bonds alternate between long and short in the x and y directions (designated M n (x) and M n (y) respectively), which is associated with the antiferro 00 of the  $d_{3x^2 r^2}$  and  $d_{3y^2 r^2}$  orbitals.

determ ined self-consistently. W hen localizing an e<sub>g</sub> orbital its symmetry is automatically broken leading to a nonzero value for the local orbital order. For example if the orbital that is localized corresponds to  $d_{3z^2}$  r<sup>2</sup> then the occupation of this orbital and its partner,  $d_{x^2}$  y<sup>2</sup>, will be di erent. This di erence, because of hybridization effects, will not be equal to unity as it would be in a fully localized picture.

The SIC-LSD provides the quantitative comparison of all energies for LaM nO $_3$ . This material has a distorted cubic structure with OO as shown in Fig. 1 and is an A-type antiferrom agnet (A-AFM) such that the moments in the x-y planes shown in Fig. 1 are ordered ferrom agnetically and the planes are stacked antiferrom agnetically

TABLE I: Summary of all energy scales in LaM nO<sub>3</sub>.

Quantity	Energy gain	
	(m R y per form ula unit)	
E lectronic energy gain		
due to the distortion	40	
Localisation energy	20	
Purely electronic contribution to		
the orbital ordering energy	5	
Relative stability of		
the A type antiferrom agnetic		
state com pared with ferrom agnetic	1	

along the caxis. A lthough the dom inant distortion about a M n site is tetragonal there are other components so that the net symmetry is lower. We have established that the relevant energies are: change in the total energy due to the distortion, localization energy, the purely electronic contribution to the orbital ordering energy (i.e., the change in the electronic energy induced by 00 in the absence of distortion ), and the m agnetic ordering energy; these energy scales are sum m arized in Table I.

The largest electronic energy is that due to the distortion i.e., the gain in energy by imposing 00 in the distorted crystal structure. The second largest energy in the problem is the localization energy which is the difference between the energies of localized and delocalized  $e_{\alpha}$  states. The value is about 20 m R y per form ula unit, depending slightly on the state of magnetisation and distortion. The magnetisation com es last, as the smallest energy scale, behind the purely electronic contribution to the orbital ordering energy. The oxygen displacem ents around site M n (x) are such that the site sym m etry has a large, 2 xx yy zz, distortion, as well as other sm aller distortions that break the symmetry between y and z. The Mn(y) site has a similar distortion. Table II contains all SIC-LSD energies when a given  $e_{g}$  orbital has been localized on a given site, for A-AFM spin ordering. All calculations were done for the experim ental distorted structure.[9]

The following points may be seen from this table. First, the most favourable state is the antiferro orbital ordering (AF 00) on the correct site coupled with antiferrom agnetic spin ordering as observed experimentally. Second, the results for scenarios 6 and 7 should be identical from symmetry. They were calculated independently and the di erence between them represents an estimate of the error on our calculations; the same is true for scenarios 9 and 10. Third, the size of the total electronic energy favouring the orbital ordering is found from the most and least favorable AF scenarios 1 and 4, which differ by 78 m Ry, half of which is then the energy gain due to 00, i.e. the largest energy scale of Table I. M ore explicitly, the states in scenarios 1 and 3 have identical

TABLE II: Results for several scenarios where the three  $t_{2g}$  orbitals and an additonal  $e_g$  state are localized on the m anganese atom s in fully distorted A -AFM structure of LaM nO<sub>3</sub>. The rst colum n gives the num bering of the scenarios which involve AF 00 and ferro (F) 00.Colum ns 2 and 3 indicate which  $e_g$  orbital is localized on the m anganese atom s with the long m anganese-oxygen bonds in the x and y directions respectively. The relative energies E, with respect to the ground state with the localized  $d_{3x^2}$   $_{r^2}$  orbital on the M n (x) sites and the  $d_{3y^2}$   $_{r^2}$  state on the M n (y) atom s, is displayed in colum n 4 (A -AFM).Colum n 5 refers to relative energies E d obtained from a localized m odel which incorporates only the orbital ordering in a purely tetragonal distortion.(see text)

				A-AFM	
	#	M n (x)	Mn(y)	E (m R y)	E d (m R y)
AF OO	1	$d_{3x^2} r^2$	d <sub>3y<sup>2</sup> r<sup>2</sup></sub>	0	0
	2	$d_{z^2 x^2}$	$d_{y^2}$ $z^2$	8.5	20
	3	d <sub>3y<sup>2</sup> r<sup>2</sup></sub>	d <sub>3x<sup>2</sup> r<sup>2</sup></sub>	65.2	59
	4	$d_{y^2 z^2}$	$d_{z^2 x^2}$	78.1	78
F 0 0	5	$d_{x^2 y^2}$	$d_{x^2 y^2}$	27.2	20
	6	$d_{3x^2}$ r <sup>2</sup>	$d_{3x^2}$ r <sup>2</sup>	39.7	29
	7	d <sub>3y<sup>2</sup> r<sup>2</sup></sub>	d <sub>3y<sup>2</sup> r<sup>2</sup></sub>	40.5	29
	8	d <sub>3z<sup>2</sup> r<sup>2</sup></sub>	d <sub>3z<sup>2</sup> r<sup>2</sup></sub>	49.5	59
	9	$d_{z^2 x^2}$	$d_{z^2 x^2}$	56.6	49
	10	$d_{y^2 z^2}$	$d_{y^2 z^2}$	57.3	49

pattern of antiferro orbits. The di erence between them is that in the form er case the lobes of the orbits m atch the lattice distortion, while in the latter case the orbit is m isaligned with respect to the distortion. B and structure e ects favour these states equally and the di erence in their energies represents the importance of the lattice distortion for the 00 energy.

The energy scale that characterises the stability of A-AFM versus FM is the sm allest energy scale, at 1 m R y, which is similar to energies that gave correct exchange constants for N iO (100) surface.[10] Thus, the ordering sequence of the row s will be the same for the A-AFM and the FM structures, which indicates that the dom inant cause of the orbital ordering is not the A-AFM m agnetic structure, as has been postulated.[11, 12]

It is instructive to see how far a localized model that assumes only a locally pure tetragonal distortion can account for the ab initio results. The energy per site is given by  $u = u_0$   $u_D \cos 2$  where  $u_0$  and  $u_D$  are the energies that do not and do depend on the distortion respectively. The angle de nest the orbit. For the site M n (x) we have  $= 0 : d_{3x^2} r^2$ ,  $= = 6 : d_{x^2} y^2; d_{x^2} z^2$ ,  $= 2 = 3 : d_{3y^2} r^2; d_{3z^2} r^2$ ,  $= = 2 : d_{y^2} z^2$ , and equivalently for the M n (y) site. The energies of scenarios 1 and 4 m ay be used to  $x u_0 = u_D = 39 \text{ m Ry for}$ the A-AFM phase. The results given in column 5 of Table II are found using this expression. It is seen that the order of energies obtained by this simple model reproduces the trends seen in the ab initio results. Moreover, most ab initio energies lie within 10 mRy of this very simple model. It appears that the discrepancy between the model and the rst principles results is mostly due to other distortions than tetragonal. In order to investigate this we have performed ab initio calculations for a crystal with a pure tetragonal distortion (of the observed m agnitude). In this case we found a slightly increased value for  $u_D$  (42 mRy) and the deviations between the m odeland the rst principles calculation are reduced to 5 mRy, for all scenarios. The size of these rem nant energy

uctuations designates the scale of the band electrons' contribution to the total energy. The imposed 00, lattice distortion and magnetic structure induce changes to the conduction electron states, which leads to changes of the order of 5 m Ry to the total energy. This represents the third energy scale of Table I, which is the second sm allest of the energy scales considered. Another estim ate for the band-electronic elects was obtained by evaluating the 00 total energy variations in the cubic phase. Our calculations gave 3.7 and 8.3 m Ry in this case, for FM and A-AFM ordering respectively, i.e. 00 is drastically suppressed without the lattice distortion.

To proceed with the analysis of the energetics of 00 in the manganites, we now consider the lattice distortion m ode. The strength of the orbital-lattice interaction m ay be deduced from the measured values of the elastic constants and the size of the lattice distortion. To see this, we follow Ref. 13 and consider an expansion of the total energy of an electronic system at T = 0 in terms of a local distortion in the unit cell at R<sub>i</sub>, i The restoring force for that m ode is characterized by the force constant K, and the elastic energy of the distortion has a simple harm onic dependence on am plitude. C ountering this is the nonzero orbital order, which contributes a negative energy:

$$U_{tot} = U_0 + U_{el}(f_ig) + \frac{1}{2} X_i K(i)^2$$
  
=  $U_0 + U_{el}(0) X_i u_{ii} + \frac{1}{2} X_i K(i)^2$ : (1)

In deriving this expression we assumed that only linear terms in  $\rm _i$  were required for the 00 energy, and de ned

$$u_i = \frac{QU_{el}(f_ig)}{Q_i}:$$

At equilibrium, the elastic and 00 energiesm ust balance, and the distortion parameter is found by m inim ising the energy, i.e.,  $_{i} = \frac{u_{i}}{K}$ . Therefore the total lowering of energy due to the lattice distortion and 00 is found by substituting the above expression for  $_{i}$  into equation (1):

$$U = U_{el}(0) \quad \frac{1}{2} \underset{i}{X} K (_{i})^{2} = U_{el}(0) \quad \frac{1}{2} \underset{i}{X} u_{i i}:$$

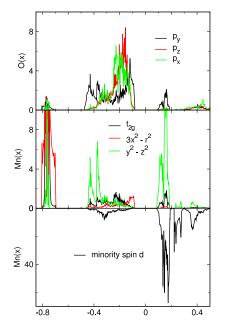


FIG.2: The orbital and spin resolved densities of states corresponding to scenario 1 (see Table II), i.e. with the  $e_{J}$  bbes oriented along the long M n-O bonds. The top panel shows the majority spin partial p densities of states for the O (x) sites, while the middle and lower panels show the majority and minority (sum med over all d orbitals) spin partial d densities of states for the M n (x) site respectively. The energies (in Ry) are relative to the Ferm ienergy at E = 0. The partial densities of states are in units of states/spin/Ry.

The distortions are known in the manganites, i 0:30 A, [9] as are also the optic phonon frequencies, leading to 12:5 eV /A<sup>2</sup>.[13] Hence, we can determ ine an ex-Κ perim entalvalue of  $u_i = 3.5 \text{ eV} / \text{A}$ . The SIC -LSD theory leads to the estim ate ui  $u_D = i$  1:8 eV/A, which is to be considered in excellent agreem ent, given the general uncertainty, not least in estimating the appropriate value of K .[13] O therw is stated, neglecting  $U_{el}(0)$ , a total Jahn-Teller ordering energy of  $\frac{1}{2}u_{D}$ 20 m R y is arrived at, which is in rather good agreem ent with the estimate of 0.48 to 0.58 eV = 35 to 43 m Ry of Ref. 13.

To shed m ore light on the hybridization e ects involved in OO, we inspect in detail the m agnetic m and orbital l quantum num bers resolved densities of states for two OO con gurations, namely scenarios 1 and 3 of Table II which are shown in Figs. 2 and 3 respectively. Localised orbitals are seen to have only m arginal admixture (below 0.1 electron) of the delocalized  $e_g$  state. The latter (in green) can be found both in the valence and conduction bands. The localized orbitals do still contribute som e weight in the valence and conduction bands of the M n (x) m a jority DOS in Figs. 2 and 3. In particular,  $t_{2g}$  states contribute to the valence and conduction bands. This re ects the slight hybridization of the  $t_{2g}$  states, show – ing that they are not of pure ionic character but acquire

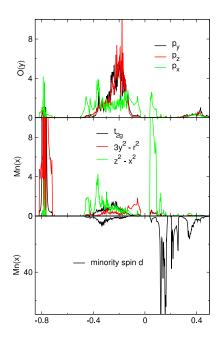


FIG. 3: The same as Fig. 2 but for scenario 3 (see Table II), i.e., the  $e_{\rm g}$  lobes are oriented along the short M n-O bonds. The top panel shows the majority spin partial p densities of states for the O (y) sites.

som e covalency. For the localized  $e_g$  state this hybridization increases and is most pronounced for  $d_{3y^2} r^2$  in F ig. 3. Here we nd  $d_{3y^2} r^2$  states in both the conduction band and at the top of the valence band, sum m ing up to 0.2 electrons. O bviously, this localized state, whose lobespoint along the short M n-O bond length, hybridizes strongly with the  $p_x$  orbital of O (y) site and this can be seen as the  $p_x$  weight in the conduction band of O (y) partial D O S in F ig. 3. In contrast the  $d_{3x^2} r^2$  weight in the valence and conduction bands for scenario 1 is less than the  $d_{3y^2} r^2$  weight in scenario 3. In scenario 1 the  $e_g$  orbital is m ore localized: 0.82 localized  $d_{3x^2} r^2$  electrons versus 0.74  $d_{3y^2} r^2$  in the D O S peak around -0.8 Ry.

These results can be easily understood in terms of the 00 reducing the overlap between the localized (SIC) e<sub>g</sub> states and the 2p states of the adjacent oxygen atoms. This is rejected in the DOS of scenario 3 by the increased hybridization in the 0 2p channel around -0.8 Ry, over the whole width of the valence band and even in the conduction band (Fig. 3), in comparison with the DOS of scenario 1. Thus localized e<sub>g</sub> states which have lobes along the long manganese oxygen bonds will be energetically favourable con gurations, while those that point along the short manganese oxygen bonds will correspond to energetically unfavourable con gurations. Therefore the next two in the sequence of favourable scenarios are also antiferro 00 involving in one case d<sub>z<sup>2</sup></sub> x<sup>2</sup> and d<sub>y<sup>2</sup></sub> z<sup>2</sup>

(8.5 m Ry above the ground state) and in the other case the  $d_{3x^2}$   $r^2$  and  $d_{3y^2}$   $r^2$  but with ferrom agnetic spin arrangement (unfavourable by 1 m Ry). It is signicant that even with the ferrom agnetic spin arrangement the antiferro 00 is lowest in energy indicating again the im – portance of the JT e ect.

In sum m ary, using the SIC -LSD theory it has been possible to investigate the orbital, spin and charge ordering of distorted LaM nO3. We nd that our calculated values for the orbital energy depend strongly on the lattice distortion and are essentially independent of the magnetic order. We have used various num erical estim ates to support our claim that the Jahn Teller interaction is the dominant e ect in producing 00. The lattice e ects are big enough to account for the observed 00, m eaning that it is not necessary to invoke additional contributions of an electronic origin. This, however, should be com pared with the results of other papers, [11, 12] where it is claimed that 00 could occur from electronic e ects alone. We agree with this in so far that we also nd an electronic e ect of the correct sym m etry. How ever, we nd that the energy associated with the pure electronic e ect is relatively sm all and that the size of the effect associated with the distortion is large enough to give rise to the structural transition. In addition, this could be corroborated by comparing with independent experiments. This is an important nding for the transport in the doped m aterials because as the electrons becom e delocalised the lattice is unable to respond fast enough and one reaches the large polaron regime. On the other hand 00 that is purely electronic could coexist in the metallic phase giving rise to residual 00 and extra contributions to the scattering.

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